## 捷多邦,专业PCB打样工厂,24小时加急出货



#### N-Channel Silicon MOSFET

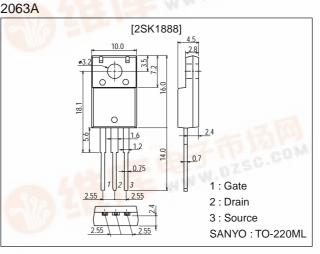
# ANYO Ultrahigh-Speed Switching Applications

## **Features**

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.
- · Micaless package facilitating mounting.

## Package Dimensions

# unit:mm



## **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		30	V
Gate-to-Source Voltage	V <sub>GSS</sub>		±15	V
Drain Current (DC)	ID		30	А
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	120	A
Allowable Power Dissipation	P-	A State of the second	2.0	W
	PD	Tc=25°C	30	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

## Electrical Characteristics at Ta = 25°C

Symbol	Conditions	Ratings			Unit
		min	typ	max	
V(BR)DSS	I <sub>D</sub> =1mA, V <sub>GS</sub> =0	30			V
V(BR)GSS	I <sub>G</sub> =±100µA, V <sub>DS</sub> =0	±15			V
IDSS	V <sub>DS</sub> =30V, V <sub>GS</sub> =0		1-5	100	μΑ
IGSS	V <sub>GS</sub> =±12V, V <sub>DS</sub> =0	10.		±10	μA
VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	1.0	10.1	2.0	V
yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =18A	17.5	29		S
R <sub>DS(on)</sub>	I <sub>D</sub> =18A, V <sub>GS</sub> =1 <mark>0V</mark>		15	25	mΩ
R <sub>DS(on)</sub>	ID=18A, VGS=4V		25	35	mΩ
	V(BR)DSS V(BR)GSS IDSS IGSS VGS(off) I yfs I RDS(on)	V(BR)DSS ID=1mA, VGS=0   V(BR)GSS IG=±100µA, VDS=0   IDSS VDS=30V, VGS=0   IGSS VGS=±12V, VDS=0   VGS(off) VDS=10V, ID=1mA     yfs   VDS=10V, ID=18A   RDS(on) ID=18A, VGS=10V	Min Min   V(BR)DSS ID=1mA, VGS=0 30   V(BR)GSS IG=±100µA, VDS=0 ±15   IDSS VDS=30V, VGS=0 10   IGSS VGS=±12V, VDS=0 1.0   VGS(off) VDS=10V, ID=1mA 1.0   I yfs VDS=10V, ID=18A 17.5   RDS(on) ID=18A, VGS=10V 17.5	Symbol Conditions min typ   V(BR)DSS ID=1mA, VGS=0 30 30   V(BR)GSS IG=±100µA, VDS=0 ±15 10   IDSS VDS=30V, VGS=0 4 10   IGSS VGS(off) VDS=10V, ID=1mA 1.0   I yfs VDS=10V, ID=18A 17.5 29   RDS(on) ID=18A, VGS=10V 15	Symbol Conditions min typ max   V(BR)DSS ID=1mA, VGS=0 30

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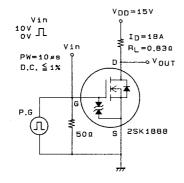
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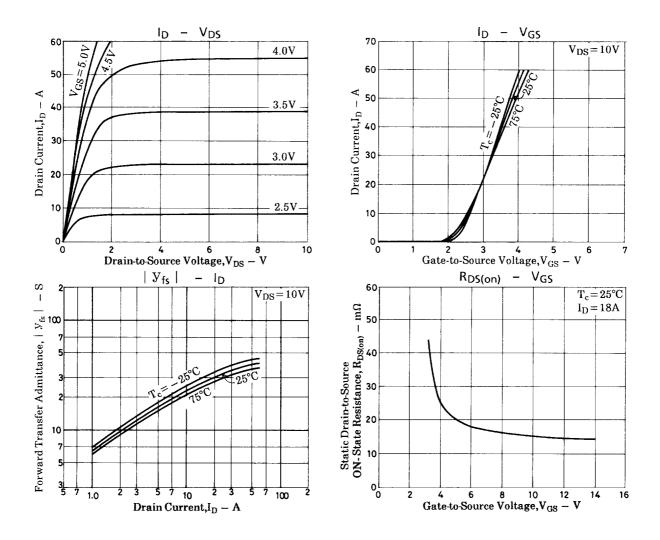
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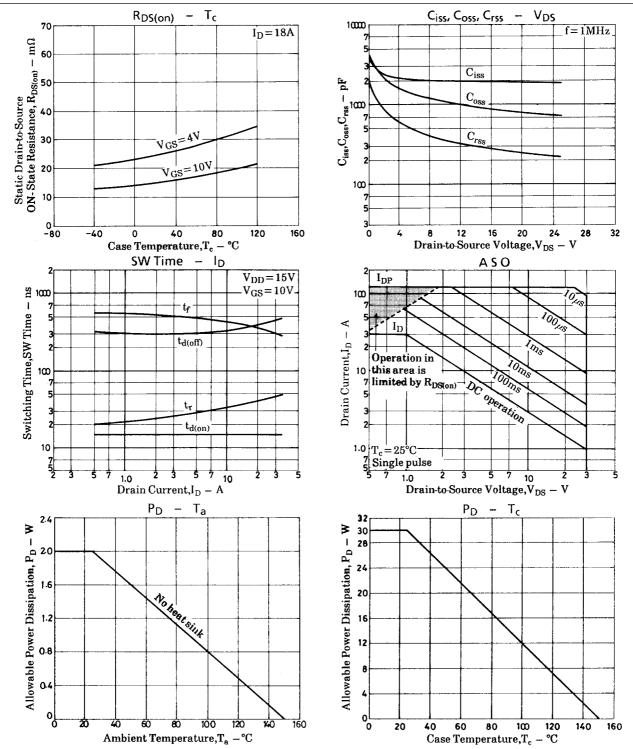
Parameter	Symbol	Conditions	Ratings			Unit
	Symbol		min	typ	max	Unit
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		2000		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		1100		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =10V, f=1MHz		360		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit		15		ns
Rise Time	tr	See specified Test Circuit		40		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit		380		ns
Fall Time	t <sub>f</sub>	See specified Test Circuit		370		ns
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =30A, V <sub>GS</sub> =0		1.0	1.5	V

## **Switching Time Test Circuit**









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